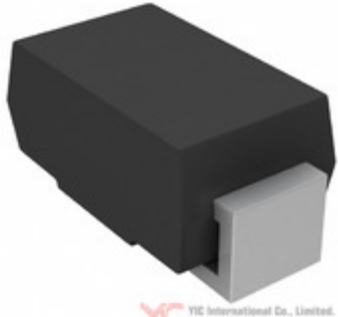

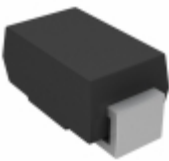
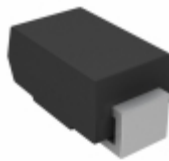
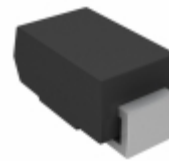
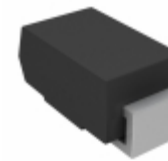

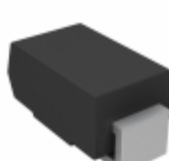

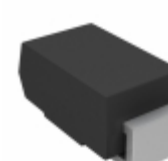
	<h2 style="color: red;">US1J-M3/61T</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: US1J-M3/61T
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: DIODE GEN PURP 600V 1A DO214AC
	Datenblätter:  US1J-M3/61T.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 12500 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	US1J-M3/61T
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 600V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	12500 pcs Stock
detaillierte Beschreibung	Diode Standard 600V 1A Surface Mount DO-214AC
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.7V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 600V
Spannung - Sperr (Vr) (max)	600V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	75ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	10pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	US1J-M3/61T-ND





US1J-M3/61T ist neu im Original, Suche US1J-M3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1J-M3/61T Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage US1J-M3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>US1J-M3/61T Vishay / Semiconductor - Diodes Division DIODE 1A 600V 75NS DO-214AC</p>	 <p>US1J-E3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>US1J/1 Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p>US1J-E3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>
 <p>US1J-TR MCC MCC SMA</p>	 <p>US1J-E3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>US1J-TP Micro Commercial Components (MCC) DIODE GEN PURP 600V 1A DO214AC</p>	 <p>US1J-M3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>

heiße Teile

Mehr

 US1D-M3/61T	 US1D-M3/61T	 US1DWF-7	 US1DWF-7	 US1G-13-F
 US1G-E3/61T	 US1G-E3/61T	 US1G-M3/61T	 US1G-M3/61T	 US1G/11T
 US1GHE3/5AT	 US1GHE3/5AT	 US1GHE3/61	 US1GHE3/61T	 US1GHE3/61T
 US1GHE3_A/H	 US1GHE3_A/H	 US1GWF-7	 US1GWF-7	 US1J-13-F
 US1J-5AT	 US1J-E3/5AT	 US1J-E3/5AT	 US1J-E3/61T	 US1J-E3/61T
 US1J-M3/61T	 US1J/11T	 US1J/61T	 US1JE-TP	 US1K-13-F
 US1K-E3/61T	 US1K-E3/61T	 US1K-E3D/H	 US1K-M3/5AT	 US1K-M3/5AT
 US1K-M3/61T	 US1K-M3/61T	 US1K/11T	 US1KSAFS-13	 US1KSAFS-13
 US1M-13-F	 US1M-13-F-73	 US1M-E3/61	 US1M-E3/61T	 US1M-E3/61T
 US1M-M3/5AT	 US1M-M3/5AT	 US1M-M3/61T	 US1M-M3/61T	 US1M-R1-10001

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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